Ordering number: EN3183A

CMOS LSI

No.3183A

LC7935AN

General-Purpose 32-Bit Shift Register Latch Driver

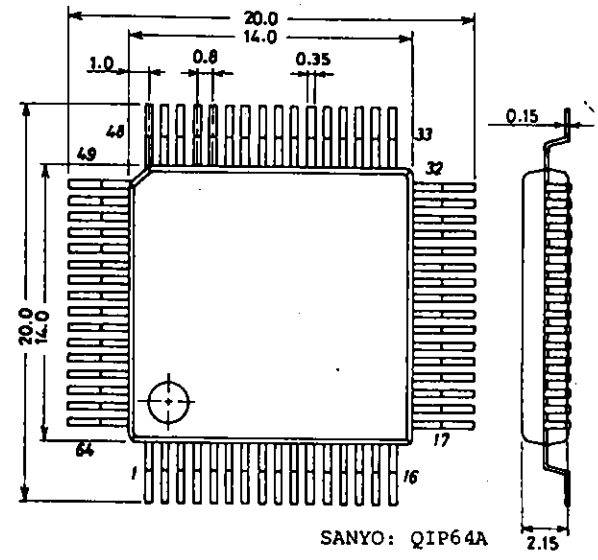
Features

- High-speed, high-voltage silicon gate CMOS device
- Contains high-speed shiftable (5MHz max) 32-bit shift register, 32-bit latch, output driver on/off control circuit, 32-bit N-channel open drain output driver.
- Serial shift data is shifted on the positive transition of the clock (CLOCK).
- 32-bit latch data is changed on the negative transition of the $\overline{\text{LATCH}}$ pad and is held on the positive transition.
- The $\overline{\text{STROBE}}$ pad, BEO pad can be used to exercise on/off control of the output driver.
- Complete separation of logic circuit GND (1 pad) and thermal driver GND (4 pads)
- Maximum ratings of driver output : $V_O = 28V$, $I_{OL} = 30mA$
- Logic unit operating voltage : $V_{DD} = 4.5$ to $5.5V$

Absolute Maximum Ratings at Ta = 25°C

				unit
Maximum Supply Voltage	V_{DD}		−0.3 to +7.0	V
Input Voltage	V_I		−0.3 to V_{DD}+0.3	V
Output Voltage	$V_{O(1)}$	S_{OUT} output	−0.3 to V_{DD}+0.3	V
	$V_{O(2)}$	D1 to D32 output, output Tr off	28	V
Output Current	I_O	D1 to D32 output,per output	30	mA
Allowable Power Dissipation	Pd max	Ta = 70°C	450	mW
Operating Temperature	Topr		−10 to +70	°C
Storage Temperature	Tstg		−35 to +125	°C

Package Dimensions 3057
(unit : mm)



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Allowable Operating Conditions at Ta = −10 to +70°C

		Pin Name		min	typ	max	unit
Supply Voltage	V_{DD}	V_{DD}		4.5		5.5	V
'H'-Level Input Voltage	V_{IH}	S_{IN},CLOCK,$\overline{LATCH}$, BEO,$\overline{STROBE}$		0.8V_{DD}		V_{DD}	V
'L'-Level Input Voltage	V_{IL}	S_{IN},CLOCK,$\overline{LATCH}$, BEO,$\overline{STROBE}$		V_{SS}(L)		0.2V_{DD}	V
Clock Frequency	f_{CLK}	CLOCK	Duty : 50%			5.0	MHz
Clock Pulse Width	$t_{W\phi}$	CLOCK		75			ns
Clock Rise/Fall Time	t_r,t_f	CLOCK				200	ns
Data Setup Time	t_{DS}	S_{IN},CLOCK		100			ns
Data Hold Time	t_{DH}	S_{IN},CLOCK		50			ns
Latch Pulse Width	t_{WL}	$\overline{LATCH}$		100			ns

Electrical Characteristics at Ta = 25°C

		Pin Name		min	typ	max	unit
'H'-Level Input Current	I_{IH}(1)	S_{IN},CLOCK,$\overline{LATCH}$				10	μA
	I_{IH}(2)	BEO		12		72	μA
'L'-Level Input Current	I_{IL}(1)	S_{IN},CLOCK,$\overline{LATCH}$		−10			μA
	I_{IL}(2)	$\overline{STROBE}$		−72		−12	μA
'H'-Level Output Voltage	V_{OH}	S_{OUT}	V_{DD}=5V,I_{OH}=−0.5mA	V_{DD}−0.5			V
'L'-Level Output Voltage	V_{OL}(1)	S_{OUT}	V_{DD}=5V,I_{OL}=0.5mA			0.5	V
	V_{OL}(2)	D1 to D32	V_{DD}=5V,I_{OL}=30mA			0.5	V
Output OFF-State Leakage Current	I_{OFF}	D1 to D32	V_O=24V			20	μA
Input Capacitance	C_{IN}		CLOCK		5.0		pF
Operating Current Dissipation	I_{DD}	V_{DD}	V_{DD}=5V,f_{CLK}=5MHz, all outputs : no load			5	mA

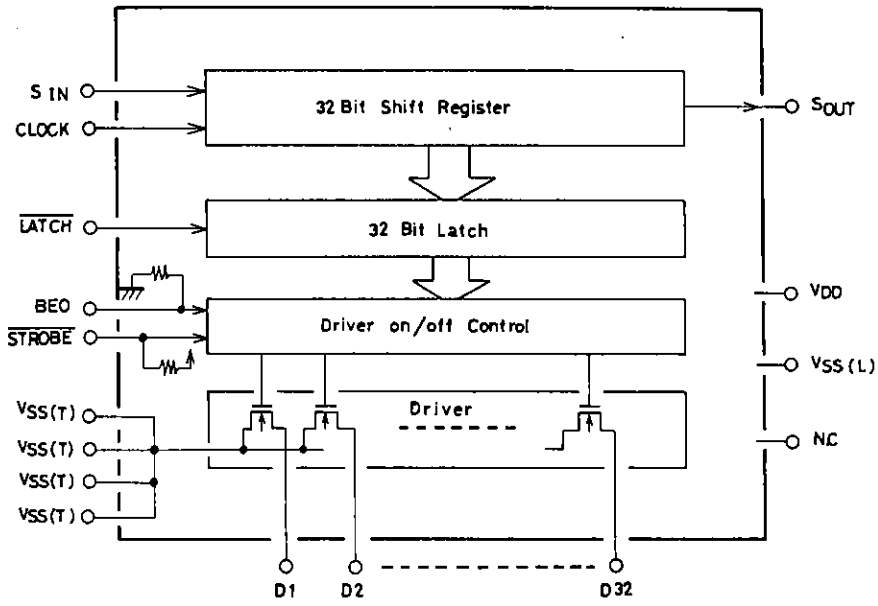
Switching Characteristics at Ta = 25°C

		Pin Name		min	typ	max	unit
Clock Latch Delay Width	t_{CL}	CLOCK, $\overline{LATCH}$	V_{DD}=5V	100			ns
Latch Clock Delay Width	t_{LC}	CLOCK, $\overline{LATCH}$	V_{DD}=5V	0			ns
'H'-Level Output Propagation Delay Time	t_{PLH}(1)	LATCH, D1 to D32	V_{DD}=5V,Dn: R_L=1.0kΩ, C_L=15pF			400	ns
	t_{PLH}(2)	BEO, $\overline{STROBE}$	V_{DD}=5V,Dn: R_L=1.0kΩ, C_L=15pF			300	ns
	t_{PLH}(3)	CLOCK, S_{OUT}	V_{DD}=5V,S_{OUT}: C_L=15pF			200	ns
'L'-Level Output Propagation Delay Time	t_{PHL}(1)	$\overline{LATCH}$, D1 to D32	V_{DD}=5V,Dn: R_L=1.0kΩ, C_L=15pF			200	ns
	t_{PHL}(2)	BEO, $\overline{STROBE}$ D1 to D32	V_{DD}=5V,Dn: R_L=1.0kΩ, C_L=15pF			100	ns
	t_{PHL}(3)	CLOCK, S_{OUT}	V_{DD}=5V,S_{OUT}: C_L=15pF			200	ns

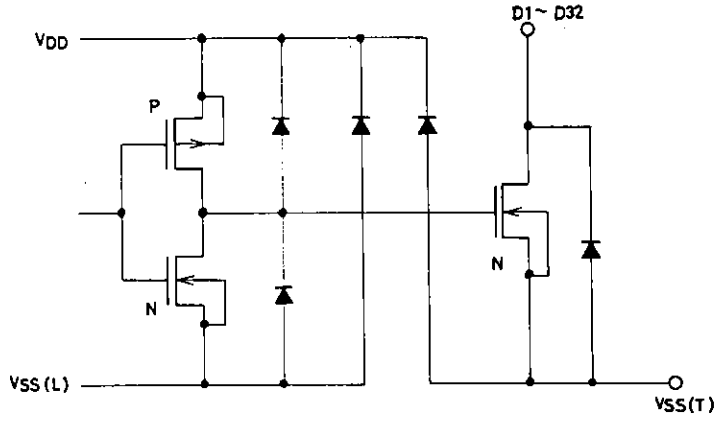
Driver ON/OFF Truth Table

Latch Data (Q)	BEO	$\overline{STROBE}$	Driver
0	0	0	OFF
1	0	0	OFF
0	1	0	OFF
1	1	0	ON Driver on
0	0	1	OFF
1	0	1	OFF
0	1	1	OFF
1	1	1	OFF

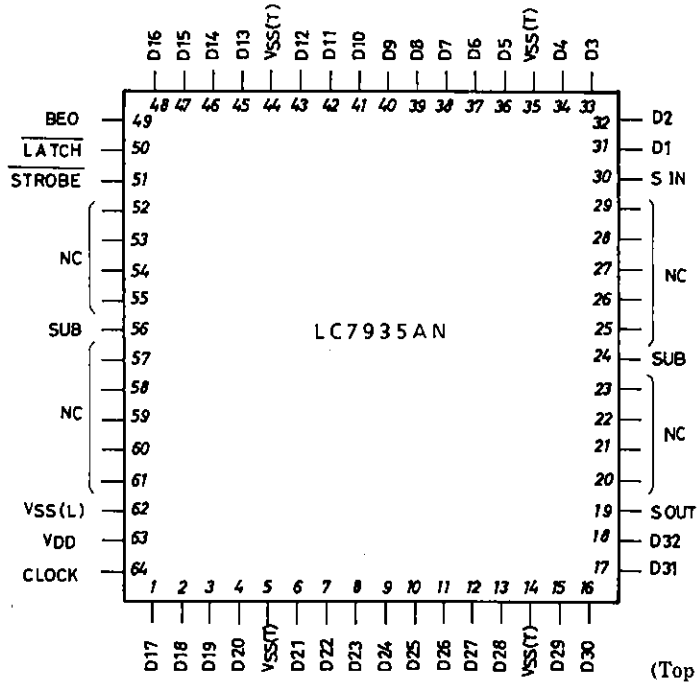
Equivalent Circuit Block Diagram



Output Driver Section Equivalent Circuit



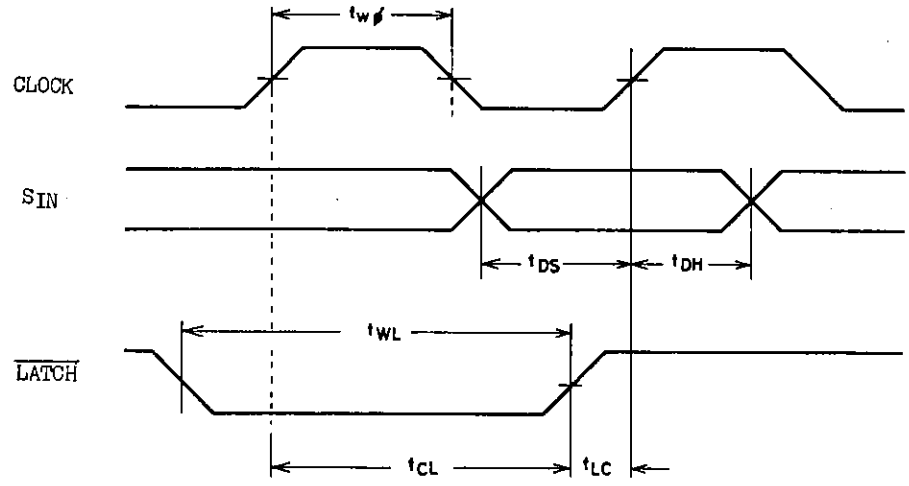
Pin Assignment



(Top View)

Note: SUB pin and NC pin must be kept open. [SUB pin is connected to the substrate (V_{DD}).]

Input Data Timing Chart



Output Data Timing Chart